

TOSHIBA

TC74VHCT240,244AF/AFW/AFT

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

**TC74VHCT240AF, TC74VHCT240AFW, TC74VHCT240AFT
TC74VHCT244AF, TC74VHCT244AFW, TC74VHCT244AFT**

OCTAL BUS BUFFER

TC74VHCT240AF / AFW / AFT INVERTED, 3 - STATE OUTPUTS

TC74VHCT244AF / AFW / AFT NON - INVERTED, 3 - STATE OUTPUTS

(Note) The JEDEC SOP (FW) is not available in Japan.

The TC74VHCT240A and 244A are advanced high speed CMOS OCTAL BUS BUFFERS fabricated with silicon gate CMOS technology. They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The TC74VHCT240A is an inverting 3 - state buffer having two active - low output enables. The TC74VHCT244A is a non - inverting 3 - state buffer, and has two active - low output enables.

These devices are designed to be used with 3 - state memory address drivers, etc.

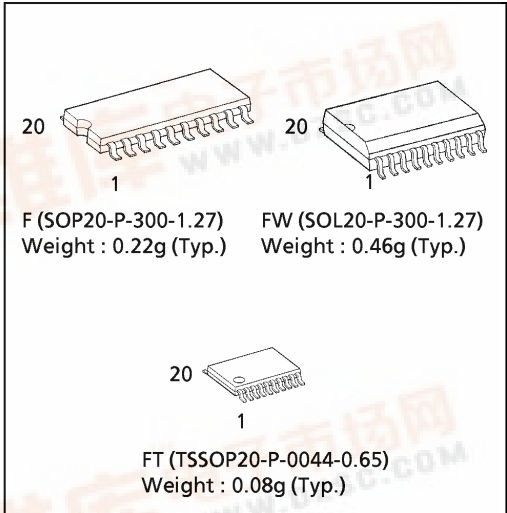
The input voltage are compatible with TTL output voltage. These devices may be used as a level converter for interfacing 3.3V to 5V system.

Input protection and output circuit ensure that 0 to 5.5V can be applied to the input and output*1 pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input / output voltages such as battery back up, hot board insertion, etc.

*1: output in off-state

FEATURES :

- High Speed..... $t_{pd} = 5.6ns$ (typ.) at $V_{CC} = 5V$
- Low Power Dissipation..... $I_{CC} = 4\mu A$ (Max.) at $T_a = 25^\circ C$
- Compatible with TTL outputs ... $V_{IL} = 0.8 V$ (Max.)
 $V_{IH} = 2.0 V$ (Min.)
- Power Down Protection is provided on all inputs and outputs
- Balanced Propagation Delays..... $t_{pLH} \approx t_{pHL}$
- Low Noise $V_{OLP} = 1.1V$ (Max.)
- Pin and Function Compatible with the 74 series (74AC / HC / F / ALS / LS etc.) 240 / 244 type.

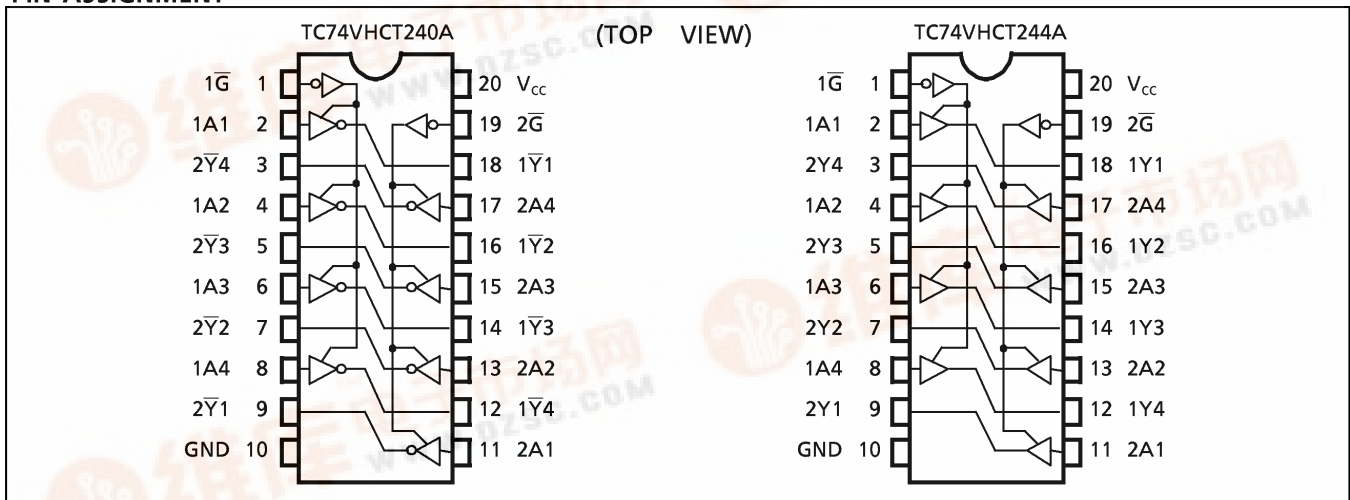


TRUTH TABLE

INPUTS		OUTPUTS	
\bar{G}	A_n	Y_n	\bar{Y}_n
L	L	L	H
L	H	H	L
H	X	Z	Z

X : Don't Care
Z : High Impedance
 Y_n : TC74VHCT244A
 \bar{Y}_n : TC74VHCT240A

PIN ASSIGNMENT

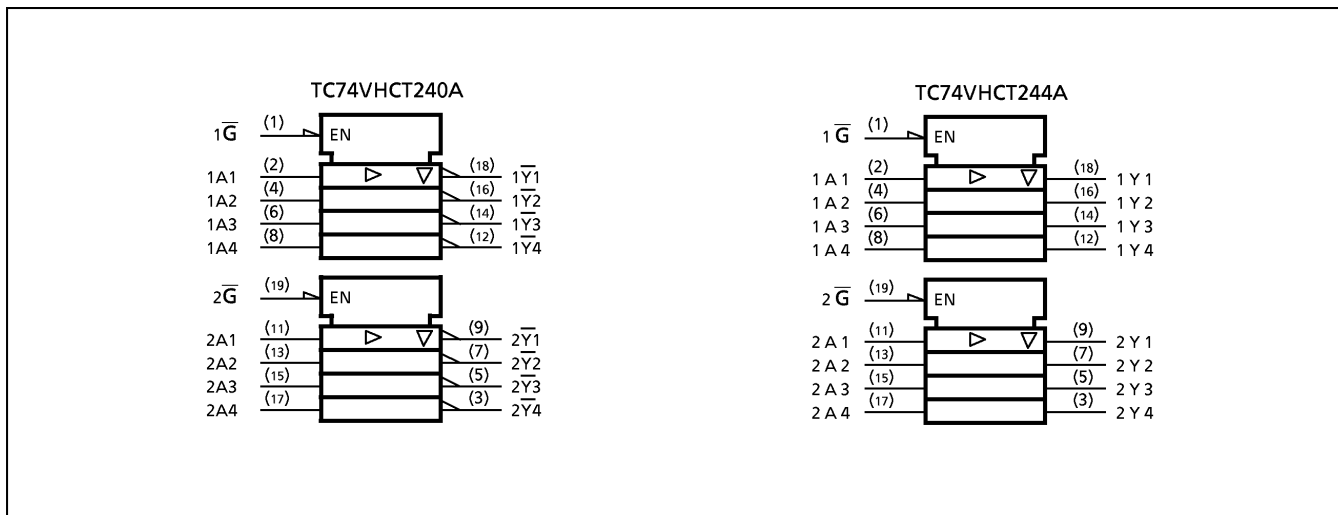


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TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.



IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V_{IN}	-0.5~7.0	V
DC Output Voltage	V_{OUT}	-0.5~7.0 (Note 1)	V
		-0.5~ V_{CC} + 0.5 (Note 2)	
Input Diode Current	I_{IK}	-20	mA
Output Diode Current	I_{OK}	±20 (Note 3)	mA
DC Output Current	I_{OUT}	±25	mA
DC Vcc/Ground Current	I_{CC}	±75	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	-65~150	°C

(Note 1) Output in Off-State

(Note 2) High or Low State. I_{OUT} absolute maximum rating must be observed.

(Note 3) $V_{OUT} < GND, V_{OUT} > V_{CC}$

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	4.5~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~5.5 (Note 4)	V
		0~ V_{CC} (Note 5)	
Operating Temperature	T_{opr}	-40~85	°C
Input Rise and Fall Time	dt / dV	0~20	ns / V

(Note 4) Output in Off-State

(Note 5) High or Low State

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DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	CONDITON		V _{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V _{IH}			4.5~5.5	2.0	—	—	2.0	—	V
Low - Level Input Voltage	V _{IL}			4.5~5.5	—	—	0.8	—	0.8	V
High - Level Output Voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50μA	4.5	4.40	4.50	—	4.40	—	V
			I _{OH} = -8mA	4.5	3.94	—	—	3.80	—	
Low - Level Output Voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50μA	4.5	—	0.0	0.10	—	0.10	V
			I _{OL} = 8mA	4.5	—	—	0.36	—	0.44	
3 - State Output Off - State Current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	—	—	±0.25	—	±2.50	μA
Input Leakage Current	I _{IN}	V _{IN} = 5.5V or GND		0~5.5	—	—	±0.1	—	±1.0	
Quiescent Supply Current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	4.0	—	40.0	
	I _{CCT}	PER INPUT : V _{IN} = 3.4V OTHER INPUT : V _{CC} or GND		5.5	—	—	1.35	—	1.50	mA
Output Leakage Current	I _{OPD}	V _{OUT} = 5.5V		0	—	—	+0.5	—	+5.0	μA

AC ELECTRICAL CHARACTERISTICS (Input t_r = t_f = 3ns)

PARAMETER	SYMBOL	TEST CONDITION			Ta = 25°C			Ta = -40~85°C		UNIT
		V _{CC} (V)	C _L (pF)		MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (TC74VHCT240A)	t _{pLH} t _{pHL}	5.0 ± 0.5	15	—	5.6	7.8	1.0	9.0	ns	
				50	—	6.1	8.8	1.0		10.0
Propagation Delay Time (TC74VHCT244A)	t _{pLH} t _{pHL}	5.0 ± 0.5	15	—	5.4	7.4	1.0	8.5		
				50	—	5.9	8.4	1.0		9.5
3-State Output Enable Time	t _{pZL} t _{pZH}	R _L = 1kΩ	5.0 ± 0.5	15	—	7.7	10.4	1.0		12.0
				50	—	8.2	11.4	1.0		13.0
3-State Output Disable Time	t _{pLZ} t _{pHZ}	R _L = 1kΩ	5.0 ± 0.5	50	—	8.8	11.4	1.0		13.0
Output to Output Skew	t _{osLH} t _{osHL}	(Note 6)	5.0 ± 0.5	50	—	—	1.0	—		1.0
Input Capacitance	C _{IN}				—	4	10	—		10
Output Capacitance	C _{OUT}				—	9	—	—	—	
Power Dissipation Capacitance (Note 7)	C _{PD}	TC74VHCT240A			—	19	—	—	—	
		TC74VHCT244A			—	18	—	—	—	

(Note 6) Parameter guaranteed by design. t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|

(Note 7) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 8 \text{ (per bit)}$$

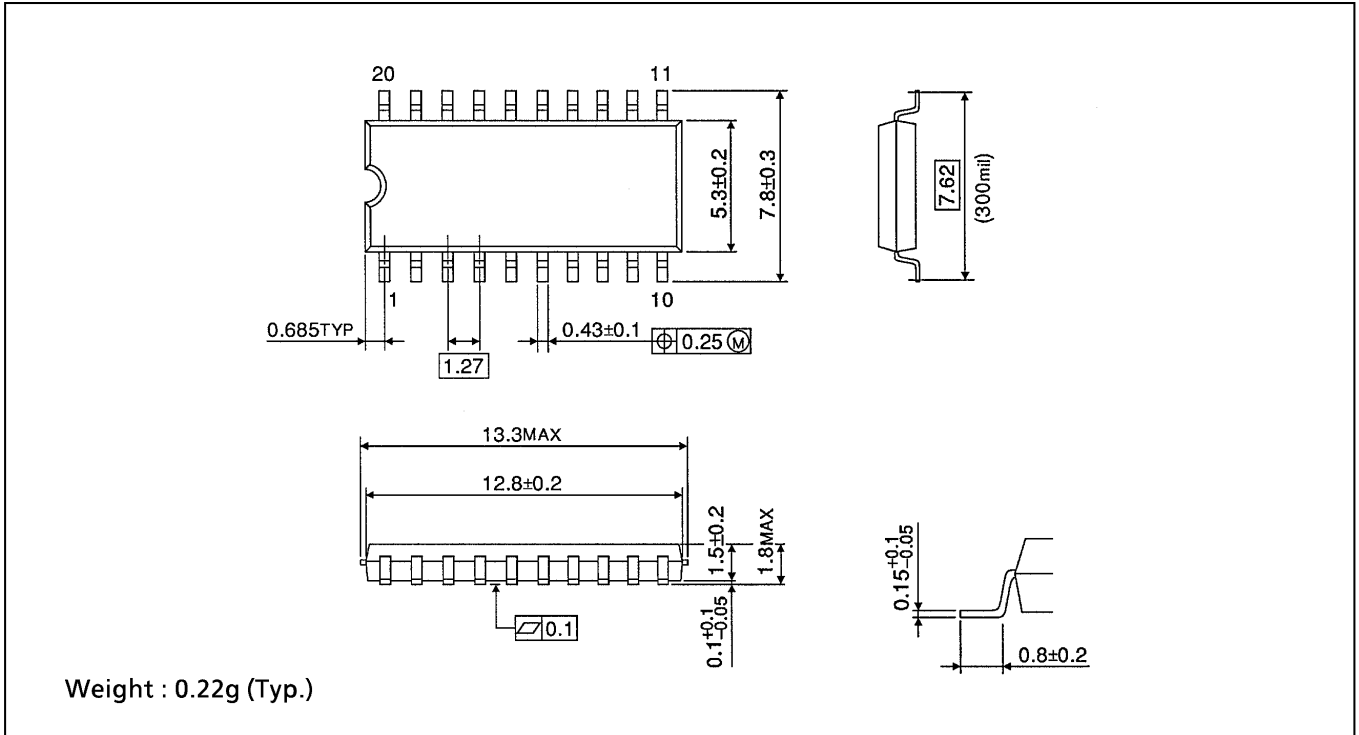
NOISE CHARACTERISTICS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C			UNIT
			V _{CC} (V)	TYP.	LIMIT	
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	C _L = 50pF	5.0	0.8 (0.9)	1.0 (1.1)	V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	C _L = 50pF	5.0	-0.8 (-0.9)	-1.0 (-1.1)	V
Minimum High Level Dynamic Input Voltage	V _{IHD}	C _L = 50pF	5.0	—	2.0	V
Maximum Low Level Dynamic Input Voltage	V _{ILD}	C _L = 50pF	5.0	—	0.8	V

(Note) The value in () only applies to JEDEC SOP (FW) devices.

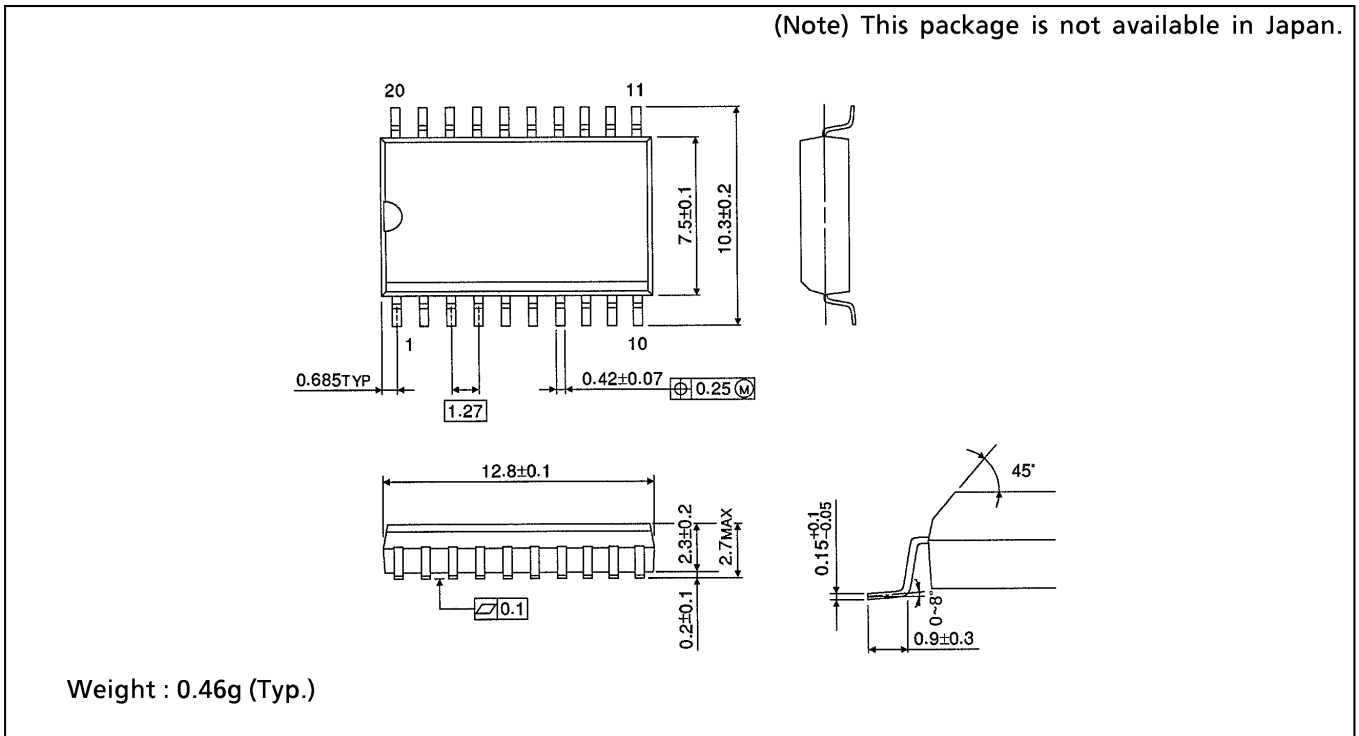
SOP 20PIN (200mil BODY) OUTLINE DRAWING (SOP20-P-300-1.27)

Unit in mm



SOP 20PIN (300mil BODY) OUTLINE DRAWING (SOL20-P-300-1.27)

Unit in mm



TSSOP 20PIN OUTLINE DRAWING (TSSOP20-P-0044-0.65)

Unit in mm

